

Tuesday Nov.4 Room A		
7:00-7:50A M	Breakfast	
7:50-7:55AM	Opening Ceremony Chair: Zhiming Wang	
7:55-8:00AM	Introduction of Frontiers in Crystal Engineering Chair: Jagadese J. Vittal	
Session: Frontiers in Crystal Engineering I Chair: Jagadese J. Vittal		
8:00-8:25AM	A01: Exotic Mechanical Properties of Molecular Crystals: A Chemist's Perspective	Pance Naumov New York University Abu Dhabi, United Arab Emirates
8:25-8:50AM	A02: Quantum Dot Photonic Devices for Optical Communications	Naokatsu Yamamoto National Institute of Information and Communications Technology, Japan
8:50-9:15AM	A03: Electron Density Analysis for Crystal Engineering: Understanding Molecular Organization and Crystalline Properties	Enrique Espinosa Nancy University, France
9:15-9:40AM	A04: Crystal Growth of III-V Compound Semiconductor Nanostructures and Transient Spin-related Optical Phenomena	Akihiro Murayama Hokkaido University, Japan
9:40-10:05 AM	A05: Functional Inclusion Complexes and Co-crystals of Bioactive Molecules	Mino R Caira University of Cape Town, South Africa
10:05-10:20AM	Session Break	
Session: General I Chair: Akihiro Murayama		
10:20 -10:45 AM	A06: Surface Stress Evolution During Structural Formation on Silicon	Hidehito Asaoka Japan Atomic Energy Agency (JAEA), Japan
10:45-11:10AM	A07: Synthesis of Nanocubes with Perovskite Structure	Kouichi Nakashima University of Yamanashi, Japan
11:10-11:35AM	A08: Dynamic Processes during Nanostructures Growth Revealed by in Situ TEM Techniques	Neng Wan Southeast University, China

11:35-12:00PM	A09: Pattern Formation of NaCl Crystals in Drying Gelatin	Sujata Tarafdar Jadavpur University, India
12:00-12:25PM	A10: Investigation of High Efficiency Perovskite-based Photovoltaic Device	Charles Surya The Hong Kong Polytechnic University, Hong Kong
12:25-13:25 PM	Lunch Break	
Session: Frontiers in Crystal Engineering II		Chair: Pance Naumov
13:25-13:50 PM	A11: New Crystals from Old: Guest-responsive Metal Organic Frameworks	Susan Bourne University of Cape Town, South Africa
13:50 -14:15 PM	A12: Non-Coulombic Ionic Crystals Composed of Complex-cation Aggregates and Inorganic-anion Aggregates	Takumi Konno Osaka University, Japan
14:15 -14:40 PM	A13: Design of Multi-Functional Stimuli-Responsive Gold Complexes	Andrea Deak Hungarian Academy of Sciences, Hungary
14:40 -15:05PM	A14: Control of Crystal Growth of L-Phenylalanine by Optical Trapping	Ken-ichi Yuyama National Chiao Tung University, Taiwan
15:05-15:20PM	Session Break	
Session: Frontiers in Crystal Engineering III		Chair: Cheng-Yong Su
15:20-15:45PM	A15: Crystals Engineering in Pharmaceutical Cocrystals	Tong-Bu Lu Sun Yat-Sen University, China
15:45-16:10PM	A16: Coordination Assembly of Crystalline MOFs and Amorphous MOGs: Order vs Disorder	Cheng-Yong Su Sun Yat-Sen University, China
16:10-16:35PM	A17: In-Situ Observation of Chemical Vapor Deposition Using Langasite Crystal Microbalance	Hitoshi Habuka Yokohama National University, Japan
16:35-17:00PM	A18: Crystal Engineering in Metalladithiolene Molecular Solids by Non-covalent Intermolecular Interactions	Tetsuro Kusamoto The University of Tokyo, Japan
17:30PM	Dinner Social	

Wednesday Nov.5 Room B		
7:00-8:00A M	Breakfast	
Session: Recent Advances in Growth of Wide Bandgap Materials I Chair: Kun-Yu Lai		
8:00-8:25AM	B01: Nonpolar A-plane ZnO Growth for LEDs	Soothan Jang Dankook University, Korea
8:25-8:50AM	B02: Epitaxial Growth of High-performance InAlN/GaN Heterostructure by Pulse-MOCVD Technique	Jincheng Zhang Xidian University, China
8:50-9:15AM	B03: Melt Grown Layered Semiconductors	Elena Borisenko Russian Academy of Sciences, Russia
9:15-9:40AM	B04: Bottom-up Nanoheteroepitaxy of GaN on Si	Kun-Yu Lai National Central University, Taiwan
9:40-10:05 AM	B05: Thorough Study of the Evolution of the Microstructure of Thick GaN Crystals as Substrate Material for Homoepitaxial Processing of GaN Devices	Elke Meissner Fraunhofer Institute for Integrated Systems and Device Technology, Germany
10:05-10:20AM	Session Break	
Session: Crystal Growth for Renewable Energy and Energy Storage I Chair: Partha Dutta		
10:20 -10:45 AM	B06: Metal Oxide Nanowires and Mesocrystals for Enhanced Energy Storage	John Wang National University of Singapore, Singapore
10:45-11:10AM	B07: Surface Processes on Electrolyte Crystals Growing from Solution	Hans Erik Lundager Madsen Faculty of Life Sciences, Denmark
11:10-11:35AM	B08: Effects of the crystalline size/degree of carbon materials on the performances of organic supercapacitors	Hsiao-Hsuan Shen National Tsinghua University, Taiwan
12:25-13:25 PM	Lunch Break	
Session: General II Chair: Zlatko Sitar		
13:25-13:50 PM	B09: Ionic Liquid-assisted Vapor Growth of Organic Single Crystals and Films	Yuji Matsumoto Tohoku University, Japan

13:50 -14:15 PM	B10: Inhibition of Crystal Growth Caused by Discontinuous Surface Tension	Noriko Akutsu Osaka Electro-Communication University, Japan
14:15 -14:40 PM	B11: Atomically Controlled Molecular Beam Epitaxy of Germanium-ferromagnetic Alloys for Spintronics Devices	Shinya Yamanda Osaka University, Japan
14:40 -15:05PM	B12: Crystallization and Crystal Growth of Lysozyme Induced by Laser Trapping	Teruki Sugiyama National Applied Research Laboratories, Taiwan
15:05-15:20PM	Session Break	
Session: Recent Advances in Growth of Wide Bandgap Materials II Chair: Satoshi Kamiyama		
15:20-15:45PM	B13: Growth and Characterization of Fluorescent SiC as A High Color-rendering Phosphor Material	Satoshi Kamiyama Meijo University, Japan
15:45-16:10PM	B14: Development of AlGaN-based Technology for Deep UV Emitters	Zlatko Sitar North Carolina State University, USA
16:10-16:35PM	B15: Hydrogen-induced Anomalous Hall effect in Co-doped ZnO	Yong Chan Cho Pusan National University, Korea
17:30PM	Dinner Social	

Wednesday Nov.5		
Room C		
7:00-8:00A M	Breakfast	
Session: General III Chair: Virginie Brize		
8:00-8:25AM	C01: Growth and Characterizaion of Hybrid Diamond-based Heterostructures	Jiri Cervenka The University of Melbourne, Australia
8:25-8:50AM	C02: A New Approach for Estimation of Substrate Curvature in Hetero-epitaxy at Elevated Temperature	Natsuko Aota Kyushu University, Japan
8:50-9:15AM	C03: Control of Crystal Size by Completely or Partially Dissolving Crystals during Batch Crystallization	Hiroshi Ooshima Osaka City University, Japan
9:15-9:40AM	C04: Kesterite $Cu_2ZnSn(S,Se)_4$ –Phase-Pure Single Crystal and Thin Film Growths	Diego Colombara University of Luxembourg, Luxembourg
9:40-10:05 AM	C05: Weak Bonds in Low-dimensional Crystals	Hui Jiang Nanyang Technological University, Singapore
10:05-10:20AM	Session Break	
Session: Nitrides Thin Films and Applications I Chair: Elisabeth Blanquet		
10:20 -10:45 AM	C06: Various Applications of Ti-Al-N Thin Films Grown from a Vapor Phase	Elisabeth Blanquet Grenoble Alpes University, France
10:45-11:10AM	C07: Growth of InGaN Quantum Dots Light-Emitting Diodes by MOVPE	Lai Wang Tsinghua University, China
11:10-11:35PM	C08: High Purity Silazane-based Releasing Nitrides Coatings for PV Silicon Crystallization	Virginie Brize LCIPV laboratory – Innovative Concepts for PV, France
11:35-12:00PM	C09: The non-polar GaN (1010) surface: Surface states and intrinsic versus extrinsic Fermi-level pinning	Holger Eisele Berlin University of Technology , Germany
12:25-13:25 PM	Lunch Break	
Session: Crystal Growth for Optoelectronic Device I Chair: Darko Makovec		

13:25-13:50 PM	C10: Understanding and Controlling Epitaxial Growth of Lattice Mismatched Materials Using InGaAs on GaAs	Itaru Kamiya Toyota Technological Institute, Japan
13:50 -14:15 PM	C11: Fabrication of Ultra-high Density InAs QDs and Its Applications	Kouichi Akahane National Institute of Information and Communications Technology, Japan
14:15 -14:40 PM	C12: Synthesis of Bi-Crystalline ZnO Nanowire Arrays on Glass substrate by Thermal Oxidation of Zinc Film: Growth Mechanism and Application	Jun Chen Sun Yat-sen University, China
14:40 -15:05PM	C13: Functional Semiconductor/Carbon-nanostructure Hybrids for Advanced Photodetection	Judy Wu University of Kansas, USA
15:05-15:20PM	Session Break	
Session: Crystal Growth in the Nano- and Micro-scale I Chair: Murali Rangarajan		
15:20-15:45PM	C14: Growth of Bimagnetic Composite Nanocrystals	Darko Makovec Jozef Stefan Institute, Slovenia
15:45-16:10PM	C15: Growth of Fullerene Nanowhiskers by LLIP Method	Kun'ichi Miyazawa National Institute for Materials Science, Japan
16:10-16:35PM	C16: CH- π , π - π and Weak Hydrogen Bonds in Crystal Engineering	M. Moazzam Naseer Quaid-i-Azam University, Pakistan
16:35-17:00PM	C17: Rational Design of Magnetic Networks Based on High-spin Mn Clusters in Mn-1,3-diol System	Gang Wu Jilin University, China
17:30PM	Dinner Social	

Wednesday Nov.5		
Room D		
7:00-8:00A M	Breakfast	
Session: Crystal Growth for Renewable Energy and Energy Storage II Chair: Partha Dutta		
8:00-8:25AM	D01: Analysis of Defects in Mono-like Silicon Ingots by Synchrotron X-ray Diffraction Imaging	Maria Tsoutsouva European Synchrotron Radiation Facility, France
8:25-8:50AM	D02: Investigation of the interface layer between Indium droplets/Si-surface prior to Si-NWs growth Using VLS Mode and Optical Simulation of the Si-NWs for Solar Cells Application	M. Ajmal Khan Japan Science and Technology Agency (JST), Japan
8:50-9:15AM	D03: Two-dimensional Layered Complex Metal Nitrides: A New Class of Thermoelectric Materials	Isao Ohkubo National Institute for Materials Science, Japan
9:15-9:40AM	D04: Nanowires with Promise for High Efficiency Photovoltaics	Magnus T. Borgstrom Lund University, Sweden
9:40-10:05 AM	D05: Ammonium Oxofluorotitanates – Open the Door to a New Strategy for the Synthesis of TiO ₂ Mesocrystals	Yanna Guo Huazhong University of Science and Technology, China
10:05-10:20AM	Session Break	
Session: Functional Materials Chair: Suja Elizabeth		
10:20 -10:45 AM	D06: Construction of New Metal-Organic Frameworks toward Multiple Functions	Xianhe Bu Nankai University, China
10:45-11:10AM	D07: Studies on Multifunctional Oxide Crystals	Suja Elizabeth Indian Institute of Science, India
11:10-11:35AM	D08: Preparation of Functionalized Magnetic Nanoparticles for Cancer Treatment	Ren-Jei Chung National Taipei University of Technology, Taiwan
11:35-12:00PM	D09: Metal-Organic Frameworks from Highly Symmetric and Multidentate Ligands: New Methodology, Structures , Properties, Perspectives	Junfeng Bai Nanjing University, China

12:00 -12:25PM	D10: Optical Functional Materials for Full Spectrum White LEDs	Partha Dutta Rensselaer Polytechnic Institute, USA
12:25-13:25 PM	Lunch Break	
Session: Recent Advances in Growth of Wide Bandgap Materials III Chair: Tomohiro Yamaguchi		
13:25-13:50 PM	D11: Recent Progress in GaN-LED with ZnO Transparent Conductive Layer (TCL)	Gang Wang Sun Yat_sen University, China
13:50 -14:15 PM	D12: RF-MBE Growth of InGaN Alloys and Fabrication of Optical Device Structures	Tomohiro Yamaguchi Kogakuin University, Japan
14:15 -14:40 PM	D13: Polarity of GaN Surfaces and Nanowires from X-ray Photoelectron Diffraction	Oleksandr Romanyuk Academy of Sciences of the Czech Republic, Czech Republic
14:40 -15:05PM	D14: Growth and Characterization of Bulk and Nano Structured ZnO Crystals for Scintillator Applications	Nobuhiko Sarukura Osaka University, Japan
15:05-15:20PM	Session Break	
Session: Crystal Growth for Renewable Energy and Energy Storage III Chair: Partha Dutta		
15:20-15:45PM	D15: Kyropoulos Crystal Growth of Silicon for Photovoltaics	Guy Chichignoud French National Center for Scientific Research(CNRS), France
15:45-16:10PM	D16: Photocurrent and Photovoltaic Properties of Ferroelectric BiFeO ₃ -based Thin Films Grown on Si-based Substrates	Wataru Sakamoto Nagoya University, Japan
16:10-16:35PM	D17: An Interpenetrated MOF-5 Framework Constructed from an Anthracene-based carboxylate Ligand for Gas absorption	Liangliang Zhang China University of Petroleum (East China), China
17:30PM	Dinner Social	

Thursday Nov.6 Room B		
7:00-8:00A M	Breakfast	
Session: Crystal Growth in the Nano- and Micro-scale II Chair: Murali Rangarajan		
8:00-8:25AM	B16: Electrodeposited Nano- and Micro-structured crystals of Bismuth on Polycrystalline Copper: Morphologies and Ultratrace Sensing of Heavy Metals	Murali Rangarajan Amrita School of Engineering, India
8:25-8:50AM	B17: Hydrothermal Synthesis of Titania and Magnetite Crystals with Unique Morphologies	Makoto Kobayashi Tohoku University, Japan
8:50-9:15AM	B18: Electrochemical Co-Deposition of SnBi Alloys: Mechanism, Morphologies, Additives, and Composition	A. R. Rajamani Amrita Vishwa Vidyapeetham, India
9:15-9:40AM	B19: Laser Ablation in Liquid for Nanocrystals Synthesis and Nanostructures Fabrication	G. W. Yang Sun Yat-sen University, China
9:40-10:05 AM	B20: Spontaneous growth of Fe ₃ O ₄ nanopyramid structures	Ryota Takahashi University of Tokyo, Japan
10:05-10:20AM	Session Break	
Session: Frontiers in Crystal Engineering IV Chair: Makoto Kobayashi		
10:20 -10:45 AM	B21: Controlling the Directionality of Spontaneous Emission via a Novel Evanescent-to-propagating Light Transformation Effect in a Small Ridge/Truncated-cone Structure	Xuelun Wang National Institute of Advanced Industrial Science and Technology, Japan
10:45-11:10AM	B22: Anisotropic Strain Engineering in Si/Ge Heterostructures	Kentarou Sawano Tokyo City University, Japan
11:10-11:35AM	B23: A Novel Approach for Protein Crystallization with High-strength Hydrogels	Shigeru Sugiyama Osaka University, Japan
11:35 -12:00PM	B24: Control of Grain Boundaries in Metal Single Crystal and its Application to Transparent Conductive Electrode	Se-Young Jeong Pusan National University, Korea
12:25-13:25 PM	Lunch Break	
Session: General IV Chair: Lixin Zhang		

13:25 -13:50 PM	B25: Early Stages of Graphene and Nitride Growth on Silicon Carbide	Jacek A. Majewski University of Warsaw, Poland
13:50-14:15 PM	B26: Deposition of GaN/m-plane Sapphire Substrates via Electron Beam Deposition, and Optimization of Post-treatment Condition in Ammonia Environment	Azharul Ariff Kamarulzaman Universiti Sains Malaysia, Malaysia
14:15 -14:40 PM	B27: Nonporous but yet CO ₂ -sorbing Molecular Crystals	Hirohito Tsue Kyoto University, Japan
14:40 -15:05PM	B28: Effect of Natural and Forced Convection during Material Crystallization	Kader. Zaidat University of Grenoble Alpes, SIMAP, France
15:05-15:20PM	Session Break	
Session: Modeling and Simulation in Crystal Growth Chair: Xiaobin Niu		
15:20-15:45PM	B29: Surface Structures and the Defect Control During Epitaxy of Crystal	Lixin Zhang Nankai University, China
15:45-16:10PM	B30: Impact of Surface Phase Coexistence on the Development of Step-free Areas on Si(111)	Andreas Fissel Leibniz University of Hannover, Germany
17:30PM	Dinner Social	

Thursday Nov.6 Room C		
7:00-8:00A M	Breakfast	
Session: Recent Advances in Growth of Wide Bandgap Materials IV Chair: Daniela Gogova		
8:00-8:25AM	C18: 4H-SiC epilayers for high power bipolar device	Jawad Ul Hassan Linkoping University of Technology, Sweden
8:25-8:50AM	C19: Gallium Oxide – A Newly Rediscovered Wide Bandgap Semiconductor	Daniela Gogova Leibniz Institute for Crystal Growth, Germany
8:50-9:15AM	C20: Perspectives and Challenges of AlGaN HVPE	Eberhard Richter Leibniz-Institut für Höchstfrequenztechnik, Germany
9:15-9:40 AM	C21: InN and Related Semiconductor Alloys for Novel Photo-voltaic Cells – Low Temperature Epitaxial Growth, Characterization and Properties	Dimiter Alexandrov Lakehead University, Canada
9:40-10:05 AM	C22: Plasma-assisted Molecular Beam Epitaxy of ZnO on in-situ Grown GaN/4H-SiC Buffer Layers	Thorvald Andersson Chalmers University of Technology, Sweden
10:05-10:20AM	Session Break	
Session: Frontiers in Crystal Engineering V Chair: Eberhard Richter		
10:20-10:45AM	C23: Single Crystal Diffraction Obtained from a Powder via Magnetically Oriented Microcrystal Array	Tsunehisa Kimura Kyoto University, Japan
10:45-11:10AM	C24: Solution-air Interface Growth of Hierarchical Biomineral Structures	Guobin Ma Nanjing University, China
11:10-11:35PM	C25: Preparation and characterization of topological insulator thin film on H-terminated Si (111)	Lei Gao University of Electronic Science and Technology of China, China
12:25-13:25 PM	Lunch Break	
Session: Crystal Growth in Microgravity and at Externally Imposed Fields I Chair: Leonard F. Lindoy		
13:25-13:50 PM	C26: Melt Structure Control in Crystal Growth Process	Andrey P. Sadovskiy D. Mendeleev University of Chemical Technology of Russia, Russia

13:50 -14:15 PM	C27: Si Crystal Growth under Conditions of Reduced Melt Convection	Michael Gonik Centre for Material Science "PHOTON", Russia
14:15 -14:40 PM	C28: Study of Crystal-liquid Interfacial Free Energy and Local Structure of Liquid Metals Using Electrostatic Levitation Technique	Geun Woo Lee Korea Research Institute of Standards and Science, Korea
14:40 -15:05PM	C29: Crystal Growth of Ternary Compound Semiconductors in Low Gravity Environment	Ching-Hua Su NASA/Marshall Space Flight Center, USA
15:05-15:20PM	Session Break	
Session: High Pressure Crystal Growth and Diffraction Chair: Andrey P. Sadovskiy		
15:20-15:45PM	C30: Extended Architectures Derived from Cu(II) Complexes of 1,3-Aryl-Linked Bis- β -Diketonato Ligands: Towards a Pressure Controlled Molecular Switch	Leonard F. Lindoy University of Sydney, Australia
15:45-16:10PM	C31: High Pressure and Multiferroic Materials: A Happy Marriage	Edmondo Gilioli IMEM-CNR, Italy
16:10-16:35PM	C32: High -pressure Growth of New Layered-structure Chalcogenides	Vadim Brazhkin Russian Academy of Sciences, Russia
17:30PM	Dinner Social	

Thursday Nov.6 Room D		
7:00-8:00A M	Breakfast	
Session: Nitrides Thin Films and Applications II Chair: Elisabeth Blanquet		
8:00-8:25AM	D18: Niobium Nitride Thin Films Deposited by High Temperature Chemical Vapor Deposition	Frederic Mercier SIMaP, France
8:25-8:50AM	D19: UV-C Photodetectors and Emitters Grown on C-Al ₂ O ₃ by Plasma-assisted Molecular-beam Epitaxy	Valentin Jmerik IOFFE Physico-Technical Institute, Russia
8:50-9:15AM	D20: Nitride Quantum Dots for UV Emission and Application to LEDs	Julien Brault CNRS-CRHEA, France
9:15-9:40AM	D21: Functionalisation of HTCVD Grown Aluminium Nitride	Michel Pons Science et Ing énierie des MAt ériaux et Proc éés(SIMaP), France
9:40-10:05 AM	D22: Development of GaN-based Photocatalysts to Produce Hydrogen Energy from Water	Kazuhiro Ohkawa Tokyo University of Science, Japan
10:05-10:20AM	Session Break	
Session: General V Chair: Kazuhiro Ohkawa		
10:20 -10:45AM	D23: Control of the growth of ice by a new cryoprotector carboxylated -poly-L-lysi	Dmitry Vorontsov Lobachevsky State University of Nizhny Novgorod, Russia
10:45-11:10AM	D24: Corrosion Characterization of Tin-Silver Based Lead-Free Solders	M. A. Fazal University of Malaya, Malaysia
11:10 -11:35PM	D25: Structural, Optical and Luminescence Analysis of Ferromagnetic Mn-doped BaTiO ₃ Thin Films by RF Magnetron Sputtering	Kunjukunju Joy Mar Ivanios College, India
11:35 -12:00PM	D26: Growth and Applications of GaN-based Quantum Photonic Nanostructures	Yong-Hoon Cho Korea Advanced Institute of Science & Technology, Korea
12:25-13:25 PM	Lunch Break	
Session: Crystal Growth for Optoelectronic Device II Chair: Robin D. Rogers		

13:25-13:50 PM	D27: Growth and Noncritical Phase-matching Characteristics of Calcium Oxoborate Crystals	Zhengping Wang Shandong University, China
13:50 -14:15 PM	D28: Growth of Non Linear Optical Co-crystals of 4-Nitrophenol Adducts	Tatiana V. Timofeeva New Mexico Highlands University, USA
14:15 -14:40 PM	D29: Effect of Heat Treatment of Optical Fiber Incorporated with Au Nano-particles on Surface Plasmon Resonance	Seongmin Ju Gwangju Institute of Science and Technology, South Korea
14:40 -15:05PM	D30: Flat Flame Chemical Vapor Deposition of Meso-porous TiO ₂ Films as Anodes of the Dye-sensitized Solar Cells	Yijia Chen National Dong Hwa University, Taiwan
15:05-15:20PM	Session Break	
Session: Crystal Growth in Microgravity and at Externally Imposed Fields II Chair: Seongmin Ju		
15:20-15:45PM	D31: Numerical and Experimental Analysis of Ge-Sb Single Crystal Growth by AVC-AHP Technique	Ercan Balikci Bogazici University, Turkey
15:45-16:10PM	D32: Doped InSb Detached Crystals by VDS Technique: Physics, Physical Properties and Applications	Dattatray Gadkari Mithibai College (MITHI) , India
17:30PM	Dinner Social	

Wednesday Nov.5
Poster Session

14:30 -16:00PM	P01: Modeling of a novel AVC-AHP technique for Single Crystal Growth from melt	Igor Avetisov D.Mendeleyev University of Chemical Technology of Russia, Russia
	P02: Morphology effect on photocatalytic efficiency of nano-hematite	Yen-Hua Chen National Cheng Kung University, Taiwan
	P03: Growth of Two-dimensional Molybdenum Disulfide on Hexagonal Boron Nitride by Chemical Vapor Deposition	Hyonkwang Choi Inje University, Korea

	P04: Growth Control of Aerosol Deposited BaTiO ₃ Nanocrystals	Nam Young Kim Kwangwoon University, Korea
	P05: Influence of the bottom heater in Sapphire single Crystal Growth using Heat Exchange Method	Jae-Yong Lee Kookmin University, Korea
	P06: Control of Self-assembled Au Nanostructures on various Semiconductors via Time, Deposition Amount and Temperature variation	Jihoon Lee Kwangwoon University, Korea
	P07: Optical Spectral Filter Using Serially Coupled Ring Resonators Based on Silicon Waveguides	Sang Shin Lee Kwangwoon University, Korea
	P08: A new discrete[Co(SO ₄)(C ₁₂ H ₈ N ₂) ₂] × C ₂ H ₄ O complex and its transformation to higher dimensional coordination polymers	Natthaya Meundaeng Chiang Mai University, Thailand
	P09: Synthesis, structure characterization and photoluminescent studies of Eu ³⁺ and Tb ³⁺ doped La ₂ (C ₈ H ₄ O ₄)(C ₈ H ₃ NO ₆) ₂ (H ₂ O) ₄	Kitt Panyarat Chiang Mai University, Thailand
	P10: The Synthesis, Crystal Growth, and THz Properties of Organic DAST	Bing Teng Qingdao University, China
	P11: Formation of Ge/Si nanoscale structures at different growth conditions by molecular beam epitaxy	Vyacheslav Timofeev Siberian Branch of the Russian Academy of Sciences, Russia
17:30PM	Dinner Social	